



# JT450N120F2MHTE

## 主要参数 MAIN CHARACTERISTICS

$I_c$	450 A
$V_{CES}$	1200 V
$V_{cesat\_typ}$ ( $V_{ge}=15V$ )	1.8V

### 用途

- 电机驱动
- 伺服驱动
- UPS 电源
- 风力发电

### APPLICATIONS

- Motor Drives
- Servo Drives
- UPS System
- Wind Turbines

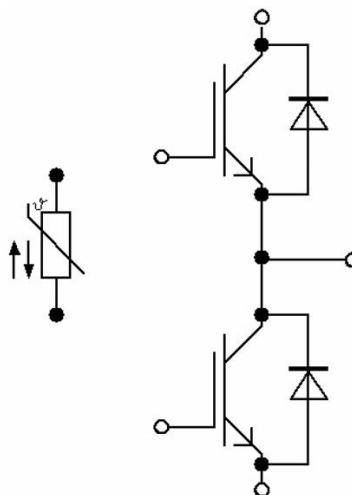
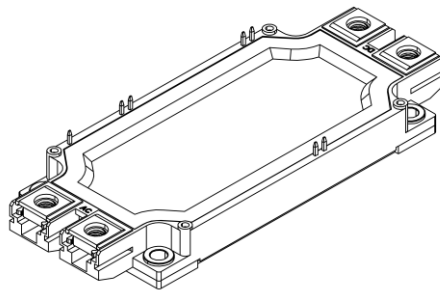
### 产品特性

- 低栅极电荷
- FS 技术
- 低通态压降,  $V_{CE(sat)}$ ,  
typ = 1.8V,  $I_c = 450A$   
and  $TC = 25^\circ C$
- RoHS 产品

### FEATURES

- Low gate charge
- FS Technology
- Low saturation voltage:  
 $V_{CE(sat)}$ , typ = 1.8V,  $I_c =$   
450A and  $TC = 25^\circ C$
- RoHS product

## 封装 Package



## 订货信息 ORDER MESSAGE

订货型号 Order codes	印记 Marking	封装 Package	包装 Packaging	器件重量 Device Weight
JT450N120F2MHTE	JT450N120F2MHTE	两单元模块	盒装	345g(typ)





# JT450N120F2MHTE

## 绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
		JT450N120F2MH1E	
最高集电极—发射极直流电压 Collector-Emmitter Voltage	V <sub>ces</sub>	1200	V
连续集电极极电流 Collector Current-continuous	I <sub>c</sub> T=25°C T=100°C	700	A
		450	A
最大脉冲集电极极电流 (注 1) Collector Current – pulse (note 1)	I <sub>CM</sub>	900	A
最高栅极发射极电压 Gate-Emmitter Voltage	V <sub>GES</sub>	±20	V
短路时间 short circuit time	tsc	10	μs
耗散功率 Power Dissipation	P <sub>D</sub> T <sub>C</sub> =25°C	2250	W
结温范围 Junction Temperature	T <sub>vjmax</sub>	175	°C
	T <sub>vj op</sub>	-40~+150	
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T <sub>L</sub>	300	°C

\*漏极电流由最高结温限制

\*Collector current limited by maximum junction temperature



# JT450N120F2MHTE

## 电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
<b>关态特性 Off –Characteristics</b>						
集电极—发射极击穿电压 Collector-Emmitter Voltage	$BV_{CES}$	$I_C=17mA, V_{GE}=0V$	1200	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{CES}/\Delta T_J$	$I_C=17mA$ , referenced to $25^\circ C$	-	0.6	-	$V/^\circ C$
零栅压下集电极漏电流 Zero Gate Voltage Collector Current	$I_{CES}$	$V_{CE}=1200V, V_{GE}=0V,$ $T_C=25^\circ C$	-	-	0.1	mA
		$T_C=100^\circ C$	-	-	2	mA
		$T_C=150^\circ C$	-	-	3	mA
正向栅极体漏电流 Gate-body leakage current, forward	$I_{GESF}$	$V_{CE}=0V, V_{GE}=20V$	-	-	200	nA
反向栅极体漏电流 Gate-body leakage current, reverse	$I_{GESR}$	$V_{CE}=0V, V_{GE}=-20V$	-	-	-200	nA
<b>通态特性 On-Characteristics</b>						
阈值电压 Gate-Emmitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}, I_C=17mA$	5.3	-	6.3	V
饱和压降（模块） Collector-Emmitter saturation Voltage	$V_{CESAT}$	$V_{GE}=15V, I_C=450A$ $T_C=25^\circ C$ $T_C=125^\circ C$ $T_C=150^\circ C$	-	1.8 2.1 2.2	2.3	V
短路电流（注2） Short Collector current（Note 2）	$I_{C(SC)}$	$V_{GE}=15V, V_{CE}=600V, t_{sc} < 10\mu s, T_C=25^\circ C$	-	2300	-	A
<b>动态特性 Dynamic Characteristics</b>						
输入电容 Input capacitance	$C_{ies}$	$V_{CE}=25V,$ $V_{GE}=0V,$ $f=1.0MHz$	-	57.5	-	nF
输出电容 Output capacitance	$C_{oes}$		-	2.1	-	nF
反向传输电容 Reverse transfer capacitance	$C_{res}$		-	1.0	-	nF





## 电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics							
开启延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{CE}=600V,$ $I_C=450A,$ $R_G=1.5\Omega$ Inductive Load	$T_C=25^\circ C$	-	275	-	ns
上升时间 Turn-On rise time	$t_r$		$T_C=25^\circ C$	-	66	-	ns
关断延迟时间 Turn-Off delay time	$t_{d(off)}$		$T_C=25^\circ C$	-	357	-	ns
下降时间 Turn-Off Fall time	$t_f$		$T_C=25^\circ C$	-	113	-	ns
开启损耗 Turn-on energy	$E_{on}$		$T_C=25^\circ C$	-	10.6	-	mJ
关断损耗 Turn-off energy	$E_{off}$		$T_C=25^\circ C$	-	32	-	mJ
总的开关损耗 Total switching energy	$E_{total}$		$T_C=25^\circ C$	-	42.6	-	mJ
栅极电荷总量 Total Gate Charge	$Q_g$		$V_{CE}=600V, I_C=450A$ $V_{GE}=15V$ (note 3, 4)	-	3.1	-	$\mu C$
内部栅极电阻 Internal gate resistance	$R_{Gint}$			2.5		$\Omega$	
反并联二极管特性及最大额定值 Anti-Parallel Diode Characteristics and Maximum Ratings							
正向压降 Diode Forward Voltage	$V_F$	$V_{GE}=0V, I_F=450A$	-	1.7	2.1		V
峰值反向恢复电流 Peak Reverse recovery current	$I_{RM}$	$V_{GE}=0V, V_R=600V I_F=450A$ $di_F/dt=3800A/\mu s$		450			A
反向恢复时间 Diode Reverse recovery time	$t_{rr}$		-	195	-		ns
反向恢复电荷 Reverse recovery charge	$Q_{rr}$		-	54	-		$\mu C$
反向恢复能量 Reverse recovery energy	$E_{rec}$			23			mJ

注释:

- 1: 脉冲宽度由最高结温限制
- 2: 两次短路之间的间隔大于 1 秒时, 允许短路测试的次数最大为 1000 次
- 3: 脉冲测试: 脉冲宽度 $\leq 300\mu s$ , 占空比 $\leq 2\%$
- 4: 基本与工作温度无关

Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: Allowed number of short circuits: <1000; time between short circuits: >1s.
- 3: Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycles  $\leq 2\%$
- 4: Essentially independent of operating temperature



**热特性 THERMAL CHARACTERISTIC**

项 目 Parameter		符 号 Symbol	最小 Min	典型 typ	最大 Max	单 位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	Per/IGBT	$R_{th(j-c)}$	-	-	0.066	$^{\circ}C/W$
管壳到散热底座的热阻 Thermal Resistance, Case to heatsink	Per/IGBT	$R_{th(c-h)}$	-	0.03	-	$^{\circ}C/W$
结到管壳的热阻 Thermal Resistance, Junction to Case	Per/FRED	$R_{th(j-c)}$	-	-	0.1	$^{\circ}C/W$
管壳到散热底座的热阻 Thermal Resistance, Case to heatsink	Per/FRED	$R_{th(c-h)}$	-	0.045	-	$^{\circ}C/W$

**热敏电阻特性 NTC Thermistor Characteristics**

项 目 Parameter		符号 Symbol	最小 Min	典型 Typ	最大 Max	单位 Unit
额定电阻值 Rated resistance	-	$R_{25^{\circ}C}$	4.75	5	5.25	kohm
时间常数	静止空气中	$\tau$	-	-	10	Sec
最大额定功率	-	$P_{max}$	-	-	10	mW
B-值 B-value	$B = [(T_a \times T_b) / (T_b - T_a)] \times \ln(R_a / R_b)$ $T_b = 50^{\circ}C \pm 0.01^{\circ}C$	$B_{25/50}$	3346.2	3380	3413.8	K
工作温度	-	-	-50	-	200	$^{\circ}C$



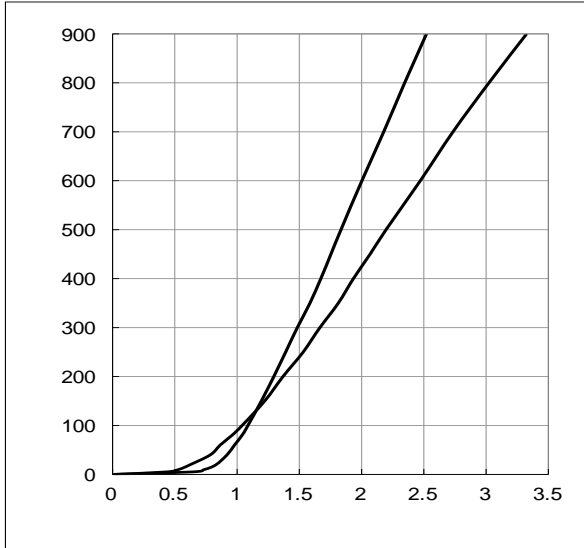
## 机械性能 Mechanical Characteristics

项目 Item	符号 Symbol	测试条件 Conditions	数值 Values			单位 Unit
			最小 Min	典型 typ	最大 Max	
安装扭矩 Mounting torque	Mt	Main terminals,M6 screw	3	-	6	Nm
安装扭矩 Mounting torque	Ms	Mounting to heat sink,M5 screw	3	-	6	Nm
爬电距离 Creepage distance	ds	Terminal to terminal	11.55	-	-	mm
		Terminal to base plate	12.32	-	-	
空隙 Clearance		Terminal to terminal	10	-	-	mm
		Terminal to base plate	10.85	-	-	
重量 Weight		-	-	345	-	g

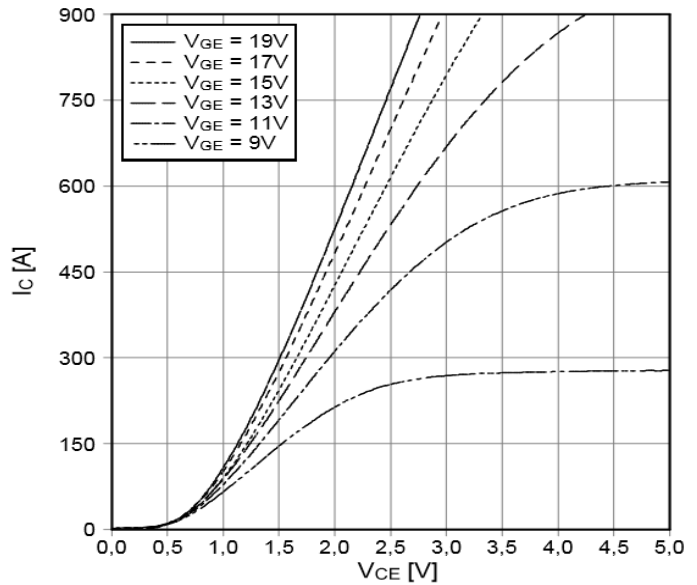




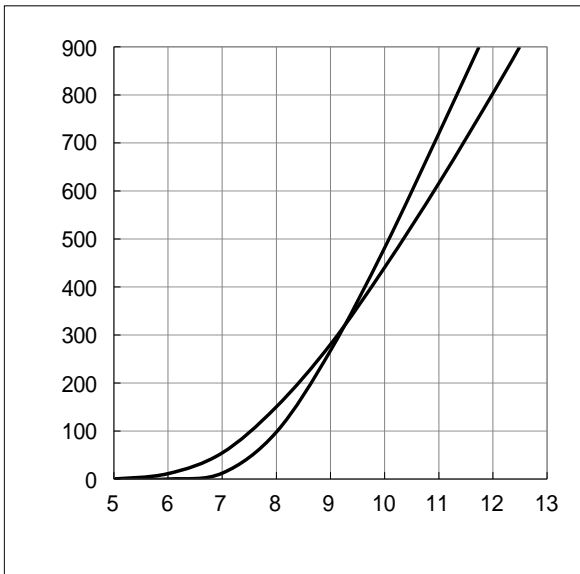
### Typical Output Characteristics( $V_{GE}=15V$ )



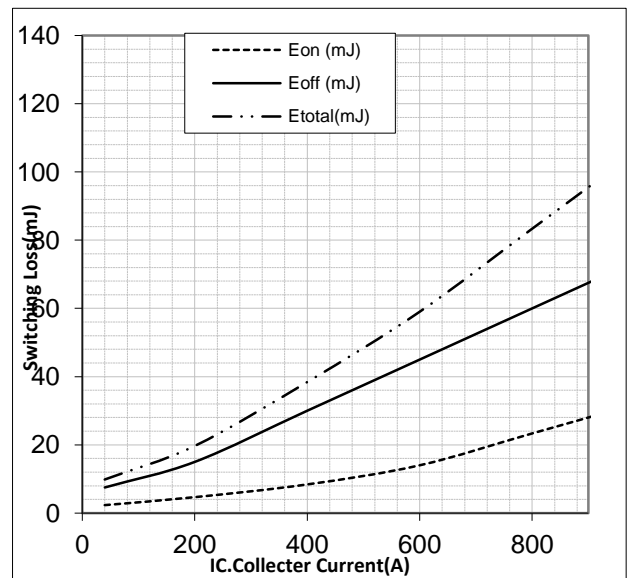
### Typical Output Characteristics( $T_j=150^\circ C$ )



### Typical Saturation Voltage Characteristics

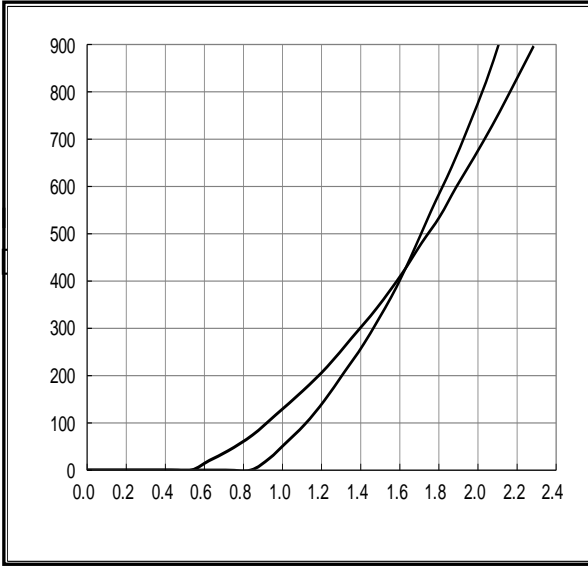


### Switching Loss vs. Collector Current ( $R_g=1.5\ \Omega$ , $V_{GE}=15V$ , $T_{vj}=25^\circ C$ )

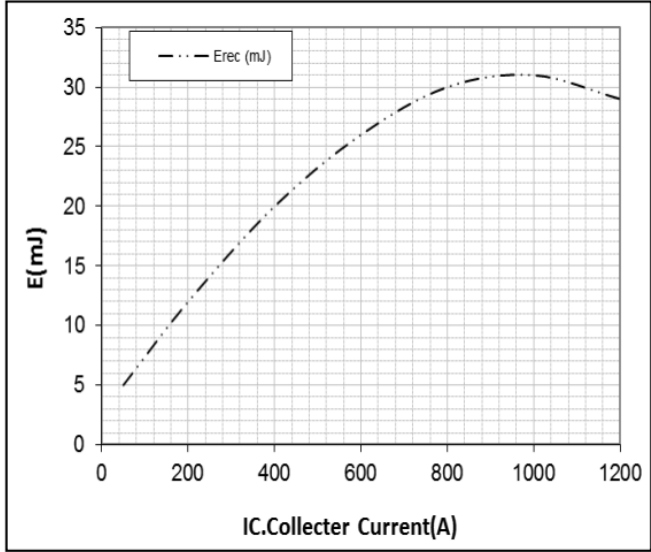




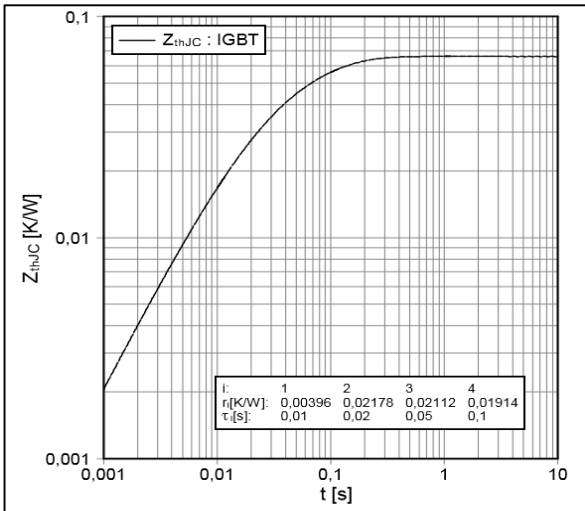
Forward Characteristics



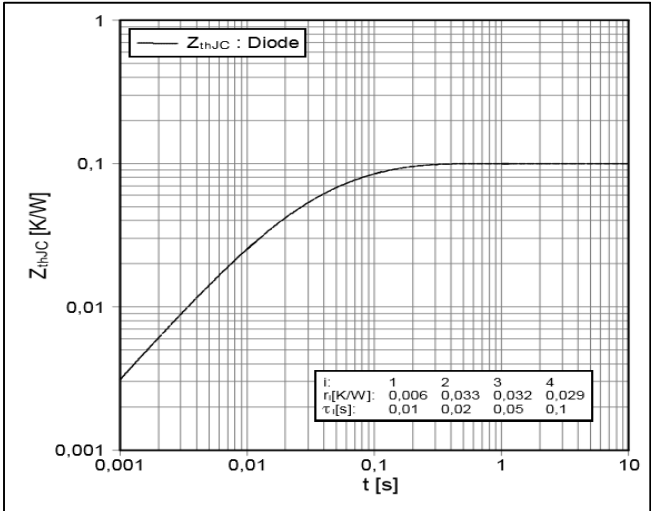
Switching Loss Diode (R<sub>Gon</sub>=1.5 Ω, V<sub>ce</sub>=600V)



Transient Thermal Impedance (IGBT)



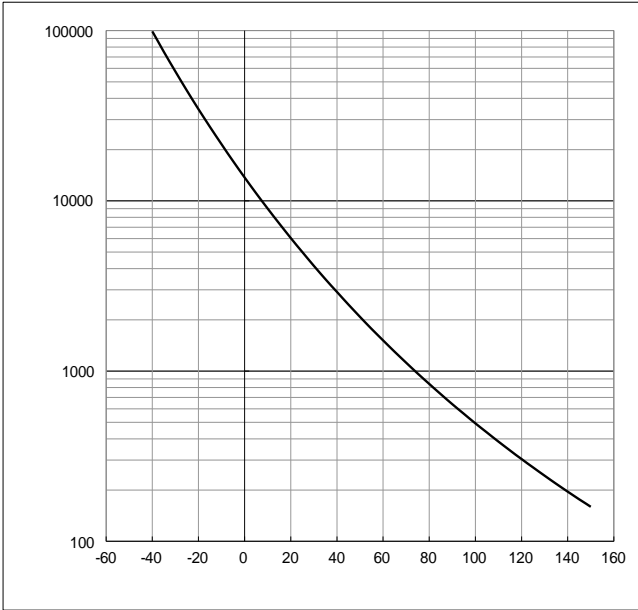
Transient Thermal Impedance (FRED)







Typ.NTC Temperature Characteristics



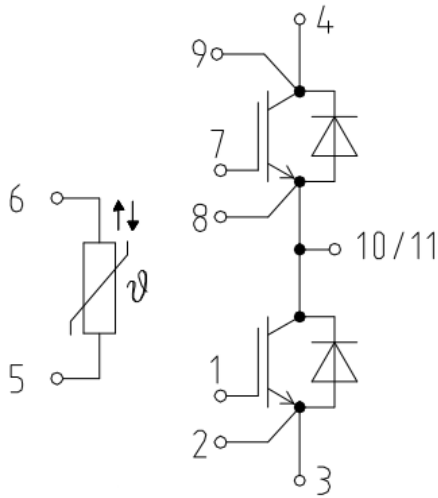


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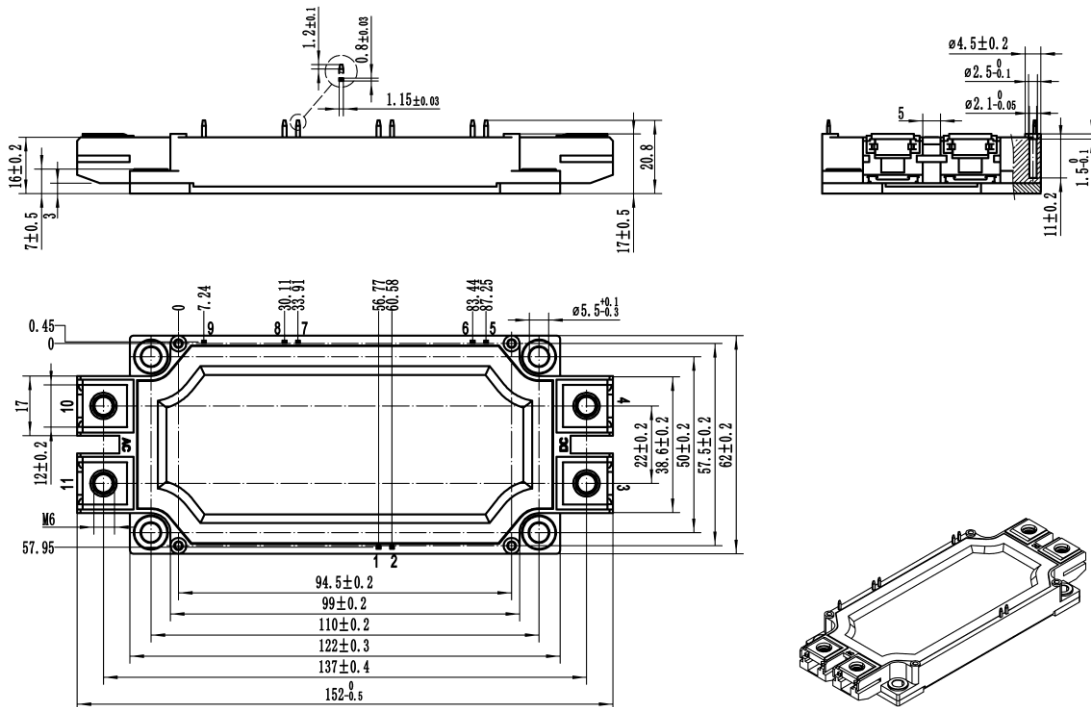
## 外形尺寸 PACKAGE MECHANICAL DATA

Circuit diagram

单位 Unit: mm



Package outlines





**注意事项**

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